National Semiconductor

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MM54HC299/MM74HC299
8-Bit TRI-STATE® Universal Shift Register

General Description

This 8-bit TRI-STATE shift/storage register utilizes advanced silicon-gate CMOS technology. Along with the low power consumption and high noise immunity of standard CMOS integrated circuits, it has the ability to drive 15 LS-TTL loads. This circuit also features operating speeds comparable to the equivalent low power Schottky device.

The MM54HC299/MM74HC299 features multiplexed inputs/outputs to achieve full 8-bit data handling in a single 20-pin package. Due to the large output drive capability and TRI-STATE feature, this device is ideally suited for interfacing with bus lines in a bus oriented system.

Two function select inputs and two output control inputs are used to choose the mode of operation as listed in the function table. Synchronous parallel loading is accomplished by taking both function select lines S0 and S1 high. This places the TRI-STATE outputs in a high impedance state, which permits data applied to the input/output lines to be clocked into the register. Reading out of the register can be done while the outputs are enabled in any mode. A direct overriding CLEAR input is provided to clear the register whether the outputs are enabled or disabled.

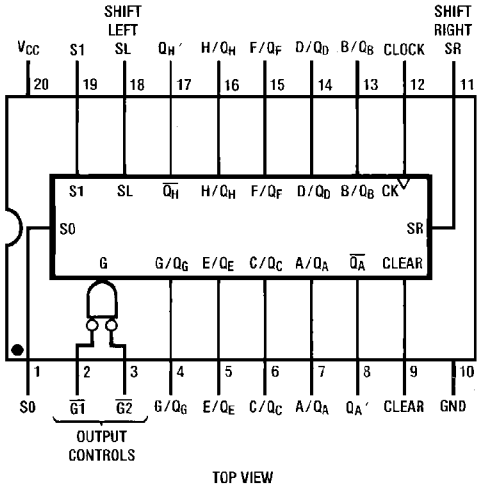
The 54HC/74HC logic family is functionally as well as pinout compatible with the standard 54LS/74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

Features

- Typical operating frequency 40 MHz
- Typical propagation delay: 20 ns
- Low quiescent current: 80 μA maximum (74HC)
- High output drive for bus applications
- Low quiescent current: 1 μA maximum

Connection Diagram

Dual-In-Line Package



TOP VIEW

TL/F/5207–1

Order Number MM54HC299 or MM74HC299

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Absolute Maximum Ratings (Notes 1 & 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V_{CC})	−0.5 to +7.0V
DC Input Voltage (V_{IN})	−1.5 to V_{CC} +1.5V
DC Output Voltage (V_{OUT})	−0.5 to V_{CC} +0.5V
Clamp Diode Current (I_{CD})	±20 mA
DC Output Current, per pin (I_{OUT})	±25 mA ($Q_{A'}$, $Q_{H'}$)
	±35 mA (others)
DC V_{CC} or GND Current, per pin (I_{CC})	±70 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C
Power Dissipation (P_D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temp. (T_L) (Soldering 10 seconds)	260°C

Operating Conditions

		Min	Max	Units
Supply Voltage (V_{CC})		2	6	V
DC Input or Output Voltage (V_{IN}, V_{OUT})		0	V_{CC}	V
Operating Temp. Range (T_A)				
MM74HC		−40	+85	°C
MM54HC		−55	+125	°C
Input Rise or Fall Times				
(t_r, t_f)	V_{CC} = 2.0V		1000	ns
	V_{CC} = 4.5V		500	ns
	V_{CC} = 6.0V		400	ns

DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	V_{CC}	T_A = 25°C	74HC T_A = −40 to 85°C	54HC T_A = −55 to 125°C	Units
				Typ	Guaranteed Limits		
V_{IH}	Minimum High Level Input Voltage		2.0V		1.5	1.5	1.5	V
			4.5V		3.15	3.15	3.15	V
			6.0V		4.2	4.2	4.2	V
V_{IL}	Maximum Low Level Input Voltage**		2.0V		0.5	0.5	0.5	V
			4.5V		1.35	1.35	1.35	V
			6.0V		1.8	1.8	1.8	V
V_{OH}	Minimum High Level Output Voltage	V_{IN} = V_{IH} or V_{IL}						
		$\|I_{OUT}\| \leq 20\ \mu A$	2.0V	2.0	1.9	1.9	1.9	V
			4.5V	4.5	4.4	4.4	4.4	V
			6.0V	6.0	5.9	5.9	5.9	V
	$Q_{A'}$ & $Q_{H'}$ Outputs	V_{IN} = V_{IH} or V_{IL}						V
		$\|I_{OUT}\| \leq 4.0$ mA	4.5V	4.2	3.98	3.84	3.7	V
		$\|I_{OUT}\| \leq 5.2$ mA	6.0V	5.7	5.48	5.34	5.2	V
	A/Q_A thru H/Q_H Outputs	V_{IN} = V_{IH} or V_{IL}						V
		$\|I_{OUT}\| \leq 6.0$ mA	4.5V	4.2	3.98	3.84	3.7	V
		$\|I_{OUT}\| \leq 7.8$ mA	6.0V	5.7	5.48	5.34	5.2	V
V_{OL}	Maximum Low Level Output Voltage	V_{IN} = V_{IH} or V_{IL}						
		$\|I_{OUT}\| \leq 20\ \mu A$	2.0V	0	0.1	0.1	0.1	V
			4.5V	0	0.1	0.1	0.1	V
			6.0V	0	0.1	0.1	0.1	V
	$Q_{A'}$ and $Q_{H'}$ Outputs	V_{IN} = V_{IH} or V_{IL}						V
		$\|I_{OUT}\| \leq 4$ mA	4.5V	0.2	0.26	0.33	0.4	V
		$\|I_{OUT}\| \leq 5.2$ mA	6.0V	0.2	0.26	0.33	0.4	V
	A/Q_A thru H/Q_H Outputs	V_{IN} = V_{IH} or V_{IL}						V
		$\|I_{OUT}\| \leq 6$ mA	4.5V	0.2	0.26	0.33	0.4	V
		$\|I_{OUT}\| \leq 7.8$ mA	6.0V	0.2	0.26	0.33	0.4	V
I_{IN}	Maximum Input Current	V_{IN} = V_{CC} or GND	6.0V		±0.1	±1.0	±1.0	μA
I_{OZ}	Maximum TRI-STATE Output Leakage Currrent	V_{OUT} = V_{CC} or GND $\overline{G}$ = V_{IH}	6.0V		±0.5	±0.5	±1.0	μA
I_{CC}	Maximum Quiescent Supply Current	V_{IN} = V_{CC} or GND I_{OUT} = 0 μA	6.0V		8.0	80	160	μA

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: −12 mW/°C from 65°C to 85°C; ceramic "J" package: −12 mW/°C from 100°C to 125°C.

Note 4: For a power supply of 5V ±10% the worst-case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst-case V_{IH} and V_{IL} occur at V_{CC} = 5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst-case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

** V_{IL} limits are currently tested at 20% of V_{CC}. The above V_{IL} specification (30% of V_{CC}) will be implemented no later than Q1, CY'89.

AC Electrical Characteristics $V_{CC}=5V$, $T_A=25°C$, $t_r=t_f=6$ ns, $C_L=45$ pF

Symbol	Parameter		Conditions	Typ	Guaranteed Limit	Units
f_{MAX}	Maximum Operating Frequency			40	25	MHz
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Clock to Q_A, or Q_H,			25	35	ns
t_{PHL}	Maximum Propagation Delay, Clear to Q_A, or Q_H,			39	40	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Clock to Q_A–Q_H		$C_L=45$ pF	25	35	ns
t_{PHL}	Maximum Propagation Delay, Clear to Q_A–Q_H		$C_L=45$ pF	28	40	ns
t_{PZL}, t_{PZH}	Maximum Enable Time		$C_L=45$ pF $R_L=1$ kΩ	10	35	ns
t_{PHZ}, t_{PLZ}	Maximum Disable Time		$C_L=5$ pF $R_L=1$ kΩ	18	25	ns
t_S	Minimum Setup Time	Select			20	ns
		Data			20	ns
t_H	Minimum Hold Time	Select			0	ns
		Data			0	ns
t_W	Minimum Pulse Width			12	20	ns
t_{REM}	Clear Removal Time				10	ns

AC Electrical Characteristics $C_L=50$ pF, $t_r=t_f=6$ ns unless otherwise specified

Symbol	Parameter	Conditions	V_{CC}	$T_A=25°C$	74HC $T_A=-40$ to 85°C	54HC $T_A=-55$ to 125°C	Units
				Typ	Guaranteed Limits		
f_{MAX}	Maximum Operating Frequency		2.0V		5	4	3.5	MHz
			4.5V		25	20	18	MHz
			6.0V		29	23	20	MHz
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Clock to Q_A, or Q_H,		2.0V	15	170	210	240	ns
			4.5V	27	38	48	54	ns
			6.0V	25	35	44	49	ns
t_{PHL}	Maximum Propagation Delay, Clear to Q_A, or Q_H,		2.0V	70	200	250	280	ns
			4.5V	30	44	55	62	ns
			6.0V	26	38	46	52	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay, Clock to Q_A–Q_H	$C_L=50$ pF	2.0V	65	170	210	240	ns
		$C_L=150$ pF	2.0V	100	206	260	295	ns
		$C_L=50$ pF	4.5V	27	38	48	54	ns
		$C_L=150$ pF	4.5V	34	46	57	66	ns
		$C_L=50$ pF	6.0V	25	35	44	49	ns
		$C_L=150$ pF	6.0V	31	39	49	55	ns
t_{PHL}	Maximum Propagation Delay, Clear to Q_A–Q_H	$C_L=50$ pF	2.0V	70	200	250	280	ns
		$C_L=150$ pF	2.0V	110	236	295	325	ns
		$C_L=50$ pF	4.5V	30	44	55	62	ns
		$C_L=150$ pF	4.5V	37	52	65	75	ns
		$C_L=50$ pF	6.0V	26	38	46	52	ns
		$C_L=150$ pF	6.0V	32	46	57	64	ns

AC Electrical Characteristic (Continued) $C_L = 50$ pF, $t_r = t_f = 6$ ns unless otherwise specified

Symbol	Parameter	Conditions	V_{CC}	$T_A = 25°C$	74HC $T_A = -40$ to $85°C$	54HC $T_A = -55$ to $125°C$	Units
				Typ	Guaranteed Limits		
t_{PZH}, t_{PZL}	Maximum Output Enable	$R_L = 1$ kΩ					
		$C_L = 50$ pF	2.0V	70	160	200	225	ns
		$C_L = 150$ pF	2.0V	90	220	275	310	ns
		$C_L = 50$ pF	4.5V	22	32	40	45	ns
		$C_L = 150$ pF	4.5V	30	44	55	62	ns
		$C_L = 50$ pF	6.0V	19	28	34	38	ns
		$C_L = 150$ pF	6.0V	24	47	47	51	ns
t_{PHZ}, t_{PLZ}	Maximum Output Disable Time	$R_L = 1$ kΩ, $C_L = 50$ pF	2.0V	70	160	200	225	ns
			4.5V	22	32	40	45	ns
			6.0V	19	28	34	38	ns
t_S	Minimum Setup Time, Data Select S_L or S_R		2.0V		100	125	140	ns
			4.5V		20	25	28	ns
			6.0V		17	21	25	ns
t_H	Minimum Hold Time, Data Select S_L or S_R		2.0V		0	0	0	ns
			4.5V		0	0	0	ns
			6.0V		0	0	0	ns
t_{REM}	Minimum Clear Removal Time		2.0V		10	10	10	ns
			4.5V		10	10	10	ns
			6.0V		10	10	10	ns
t_W	Minimum Pulse Width, Clock and Clear		2.0V		100	125	140	ns
			4.5V		20	25	28	ns
			6.0V		17	21	25	ns
t_r, t_f	Maximum Input Rise and Fall Time		2.0V		1000	1000	100	ns
			4.5V		500	500	500	ns
			6.0V		400	400	400	ns
t_{THL}, t_{TLH}	Maximum Output Rise and Fall Time, Clock		2.0V		60	75	90	ns
			4.5V		12	15	18	ns
			6.0V		10	13	15	ns
C_{PD}	Power Dissipation Capacitance	Outputs Enabled		240				pF
		Outputs Disabled		110				pF
C_{IN}	Maximum Input Capacitance Capacitance			5	10	10	10	pF
C_{OUT}	Maximum TRI-STATE Output Capacitance			15	20	20	20	pF

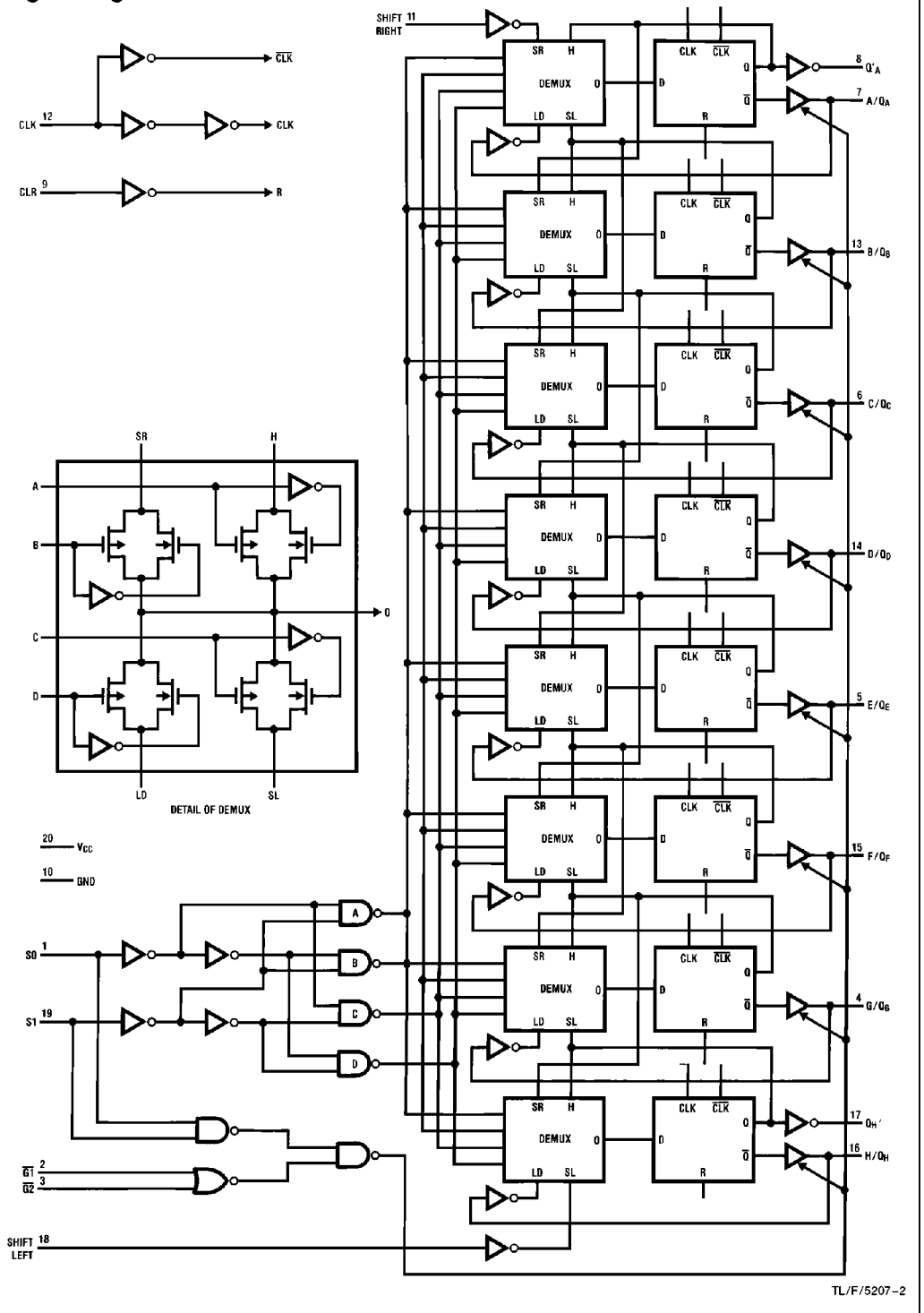
Note 5: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD}\ V_{CC}^2\ f + I_{CC}\ V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD}\ V_{CC}\ f + I_{CC}$.

Function Table

Mode	Inputs								Inputs/Outputs								Outputs	
	Clear	Function Select		Output Control		Clock	Serial		A/Q_A	B/Q_B	C/Q_C	D/Q_D	E/Q_E	F/Q_F	G/Q_G	H/Q_H	$Q_{A'}$	$Q_{H'}$
		S1	S0	$\overline{G1}$†	$\overline{G2}$†		SL	SR										
Clear	L	X	L	L	L	X	X	X	L	L	L	L	L	L	L	L	L	L
	L	L	X	L	L	X	X	X	L	L	L	L	L	L	L	L	L	L
Hold	H	L	L	L	L	X	X	X	Q_{A0}	Q_{B0}	Q_{C0}	Q_{D0}	Q_{E0}	Q_{F0}	Q_{G0}	Q_{H0}	Q_{A0}	Q_{H0}
	H	X	X	L	L	L or H	X	X	Q_{A0}	Q_{B0}	Q_{C0}	Q_{D0}	Q_{E0}	Q_{F0}	Q_{G0}	Q_{H0}	Q_{A0}	Q_{H0}
Shift Right	H	L	H	L	L	↑	X	H	H	Q_{An}	Q_{Bn}	Q_{Cn}	Q_{Dn}	Q_{En}	Q_{Fn}	Q_{Gn}	H	Q_{GN}
	H	L	H	L	L	↑	X	L	L	Q_{An}	Q_{Bn}	Q_{Cn}	Q_{Dn}	Q_{En}	Q_{Fn}	Q_{Gn}	L	Q_{GN}
Shift Left	H	H	L	L	L	↑	H	X	Q_{Bn}	Q_{Cn}	Q_{Dn}	Q_{En}	Q_{Fn}	Q_{Gn}	Q_{Hn}	H	Q_{Bn}	H
	H	H	L	L	L	↑	L	X	Q_{Bn}	Q_{Cn}	Q_{Dn}	Q_{En}	Q_{Fn}	Q_{Gn}	Q_{Hn}	L	Q_{Bn}	L
Load	H	H	H	X	X	↑	X	X	a	b	c	d	e	f	g	h	a	h

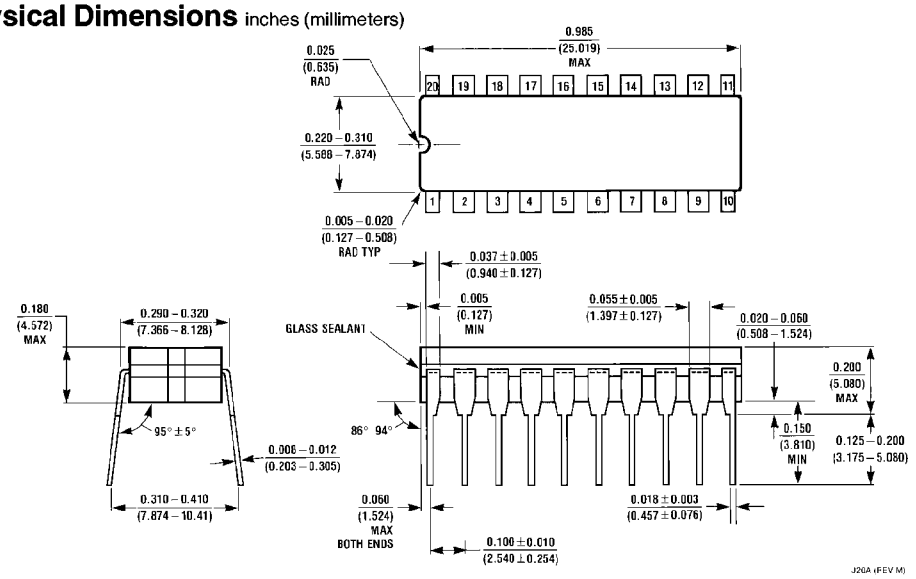
†When one or both controls are high the eight input/output terminals are disabled to the high-impedance state; however, sequential operation or clearing of the register is not affected.

Logic Diagram

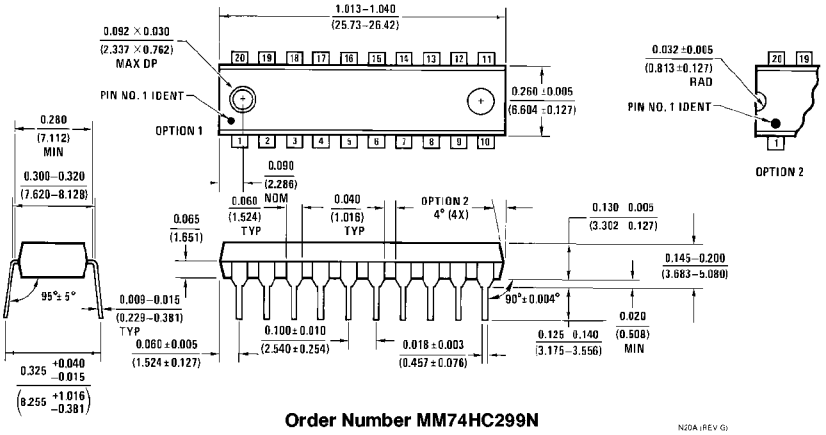


TL/F/5207–2

Physical Dimensions inches (millimeters)



Order Number MM54HC299J or MM74HC299J
NS Package J20A



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NS Package N20A

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